

# **PN3644**



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# **PNP General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
Vcbo	Collector-Base Voltage	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
lc	Collector Current - Continuous	800	mA
TJ, Tstg	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic	Мах	Units	
		PN3644	_	
P <sub>D</sub>	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W	

# PNP General Purpose Amplifie

Min

	<b>nplifier</b> (continued)	
Max	Units	

# OFF CHARACTERISTICS

Symbol

**Electrical Characteristics** 

Parameter

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	45		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	45		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	5.0		V
ICES	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, I_E = 0$ $V_{CB} = 30 \text{ V}, I_E = 0, T_A = 65^{\circ}\text{C}$		35 2.0	nA μA
I <sub>BL</sub>	Base-Cutoff Current	$V_{CE} = 30 \text{ V}, I_{C} = 0$		35	nA

TA = 25°C unless otherwise noted

**Test Conditions** 

## **ON CHARACTERISTICS\***

h <sub>FE</sub>	DC Current Gain	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ mA}$	40		
		V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1.0 mA	80		
		$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$	100		
		$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	100	300	
		$V_{CE} = 2.0 \text{ V}, I_{C} = 300 \text{ mA}$	20		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 50 \text{ mA}$	80	240	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{C} = 50 \text{ mA}, I_{B} = 2.5 \text{ mA}$		0.25	V
. ,		I <sub>C</sub> = 150 mA, I <sub>B</sub> = 15 mA		0.4	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 2.5 \text{ mA}$		1.0	V
		$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}$		1.3	V

## SMALL SIGNAL CHARACTERISTICS

Cob	Output Capacitance	$V_{CB} = 10 V, f = 140 \text{ kHz}$		8.0	pF
Cib	Input Capacitance	V <sub>BE</sub> = 0.5 V, f = 140 kHz		35	pF
h <sub>fe</sub>	Small-Signal Current Gain	$I_{C} = 20 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	2.0		

# SWITCHING CHARACTERISTICS

ton	Turn-on Time	$V_{CC} = 30 \text{ V}, \text{ I}_{C} = 300 \text{ mA},$	40	ns
t <sub>d</sub>	Delay Time	I <sub>B1</sub> = 30 mA	25	ns
tr	Rise Time	1	35	ns
t <sub>off</sub>	Turn-off Time	Vcc = 30 V, Ic = 300 mA	100	ns
ts	Storage Time	I <sub>B1</sub> = I <sub>B2</sub> = 30 mA	70	ns
t <sub>f</sub>	Fall Time	1	50	ns

\*Pulse Test: Pulse Width  $\leq 300~\mu\text{s},~\text{Duty}~\text{Cycle} \leq 2.0\%$ 



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